

Sensitivity Wavelength Range: 250-1100nm

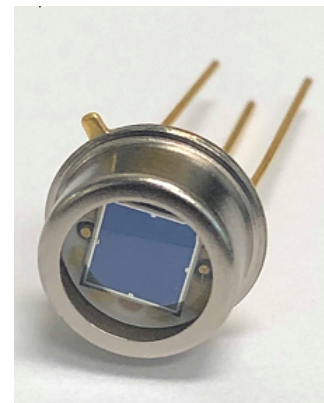
The MT03-028 is a square (3.87 x 3.87) 15mm² active area Silicon Photodiode in an isolated, hermetic TO-5 metal can package with a glass window. It is designed for applications requiring high red and near infrared (NIR) light sensitivity.

Features

- > Ultra Low Noise
- > High Shunt Resistance
- > Wide Dynamic Range
- > Broadband Spectral Coverage

Applications

- > Colorimeters
- > Photometers
- > Spectroscopy Equipment
- > Fluorescence



Absolute Maximum Ratings



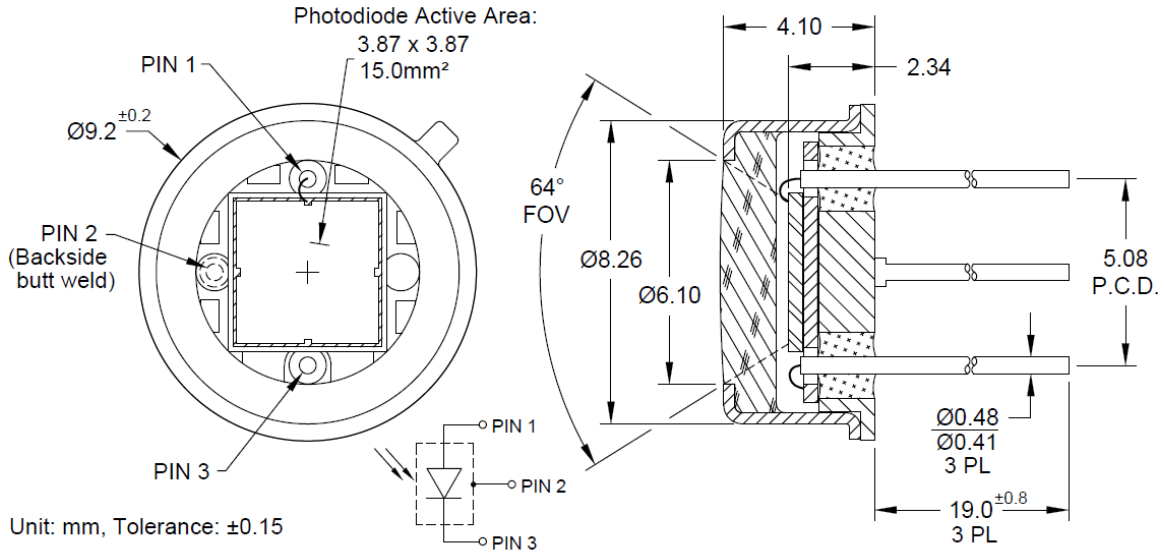
Items	Symbol	Rating	Unit
Reverse Voltage	V _R	50	V
Operating Temperature Range	T _{opr}	-40 ~ +100	°C
Storage Temperature Range	T _{stg}	-55 ~ +125	°C
Lead Soldering Temperature*1	T _{ls}	260	°C

*1: Time 5 Sec max, Position: Up to 3mm from the body.

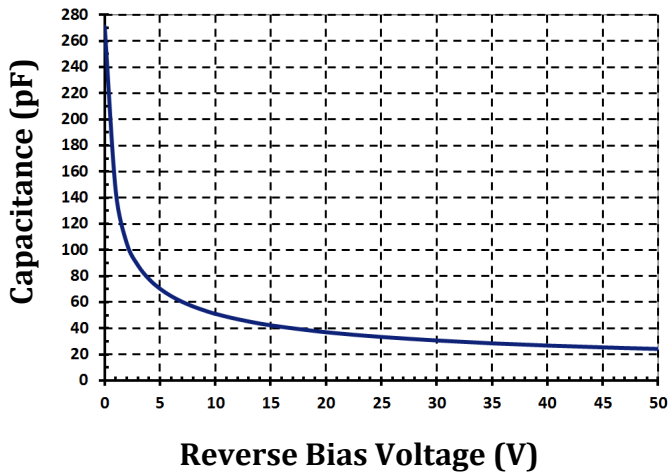
Electrical & Optical Characteristics (T_a = 23°C)

Items	Symbol	Conditions	MIN	TYP	MAX	Unit
Dark Current	I _d	V _R =5V	--	0.2	1.0	nA
Breakdown Voltage	V _(BR)	I _R =10μA	50	--	--	V
Spectral Sensitivity	λ	--	--	250-1100	--	nm
Peak Sensitivity	λ _p	--	--	940	--	nm
Wavelength Responsivity	R	V _R =0V, λ=633nm	--	0.45	--	A/W
Responsivity	R	V _R =0V, λ=950nm	--	0.64	--	A/W
Response Time @808nm	T _r	R _L =50Ω, V _R =5V	--	80	--	ns
Junction Capacitance	C _j	@ 1MHz, V _R =0V	--	275	--	pF
Junction Capacitance	C _j	@ 1MHz, V _R =5V	--	70	80	pF
Shunt Resistance	R _{sh}	V _R =10mV	500	800	--	MΩ

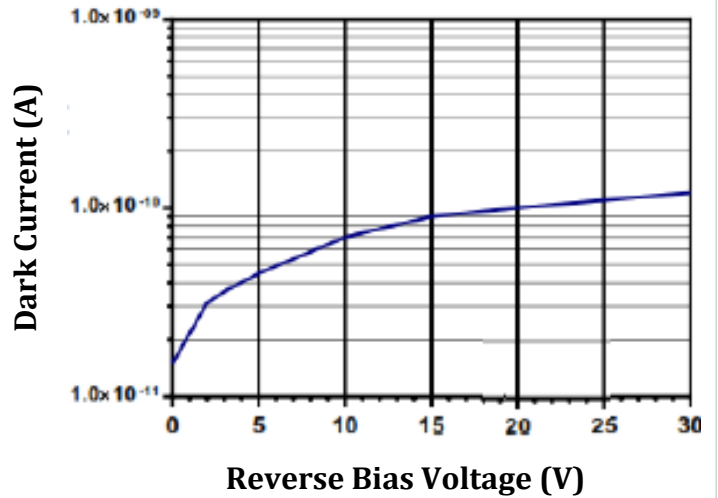
TO-5 Package Dimensions (3 Pin)



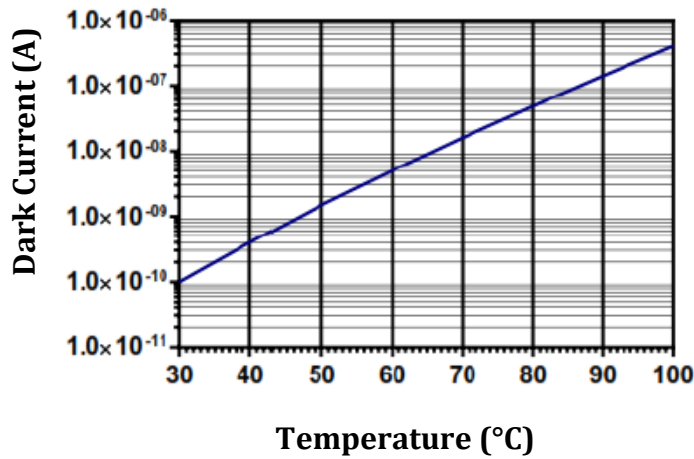
Capacitance vs Reverse Bias



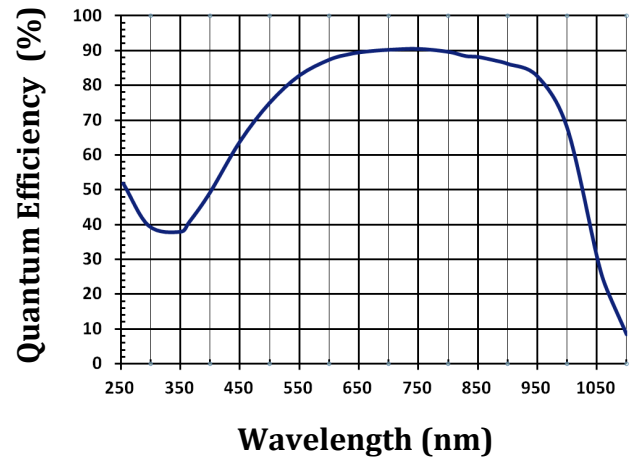
Dark Current vs Reverse Bias (23°C)



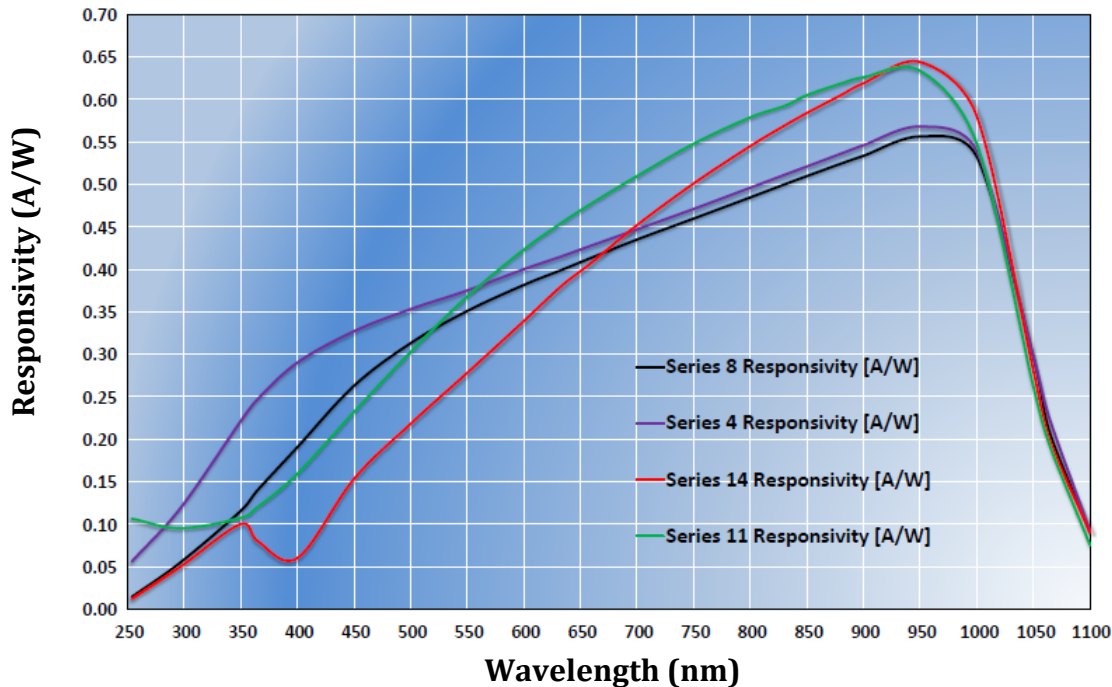
Dark Current vs Temperature ($V_r=10V$)



Series 11 Quantum Efficiency (23°C)



Photodiode Responsivity by Series



The information contained herein is subject to change without notice.

2019-04